

[DRV8880](http://www.ti.com/product/drv8880?qgpn=drv8880) SLVSD18A –JUNE 2015–REVISED JULY 2015

DRV8880 2-A Stepper Motor Driver With AutoTune™

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	-
	-
	- Non-Circular and Standard ½ Step Modes 3D Printers
- 6.5- to 45-V Operating Supply Voltage Range Office Automation Machines
- • Multiple Decay Modes to Support Any Motor • Factory Automation and Robotics
	- AutoTune™
	- Mixed Decay
	-
	-
-
-
-
- 10-, 20-, or 30-μs Off-Time
3.3-V, 10-mA LDO Regulator
 $\tilde{T}_{A} = 25^{\circ}C$).
-
- - 28 HTSSOP (PowerPAD)
	- 28 WQFN (PowerPAD)

-
- Logic Undervoltage (UVLO1) a dedicated nSLEEP pin.
-
- -
	- Retry OCP Mode
- Thermal Shutdown (TSD)
- **PARTI PARTI ENDINIGATION Pin (nFAULT)**

DRV8880 $1/16$ µstep STEP/DIR Step size Decay mode 6.5 to 45 V **Controller** *M* π იი + - Stepper Motor Driver 2.0 A AutoTune™ 2.0 A

1 Features 2 Applications

- Microstepping Stepper Motor Driver 1999 Automatic Teller and Money Handling Machines
- STEP/DIR Interface Video Security Cameras
- Up to 1/16 Microstepping Indexer Multi-Function Printers and Document Scanners
	-
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3 Description

The DRV8880 is a bipolar stepper motor driver for – Slow Decay industrial applications. The device has two N-channel

industrial applications. The device has two N-channel

power MOSFET H-bridge drivers and a microstepping power MOSFET H-bridge drivers and a microstepping Adaptive Blanking Time for Smooth Stepping indexer. The DRV8880 is capable of driving 2.0 A fullscale current or 1.4-A rms current (with proper PCB • Configurable Off-Time PWM Chopping ground plane for thermal dissipation and at ²⁴ ^V and

AutoTune™ automatically tunes stepper motors for Low-Current Sleep Mode (28 µA) optimal current regulation performance and Small Package and Footprint extending compensates for motor variation and aging effects. Additionally slow, fast, and mixed decay modes are

The STEP/DIR pins provide a simple control interface. The device can be configured in full-step up **Protection Features**

• **Protection Features**

• VM Undervoltage Lockout (UVLO2)

• provided for very low quiescent current standby using provided for very low quiescent current standby using

– Charge Pump Undervoltage (CPUV) Internal protection functions are provided for - Overcurrent Protection (OCP) andervoltage, charge pump faults, overcurrent, shortcircuits, and overtemperature. Fault conditions are – Latched OCP Mode indicated by a nFAULT pin.

Device Information[\(1\)](#page-0-0)

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Microstepping Current Waveform

An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, **44** intellectual property matters and other important disclaimers. PRODUCTION DATA.

Simplified System Diagram

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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

5 Pin Configuration and Functions

Pin Functions

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Pin Functions (continued)

External Components

(1) V_{MCU} is not a pin on the DRV8880, but a supply voltage pullup is required for open-drain output nFAULT; nFAULT may be pulled up to
V3P3

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range referenced with respect to GND (unless otherwise noted) (1)

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) Transients of ± 1 V for less than 25 ns are acceptable

6.2 ESD Ratings

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

(1) Internal logic and indexer remain active down to V_{UVLO2} (4.9 V maximum) even though the output H-bridges are disabled (2) Operational at VREF \approx 0 to 0.3 V, but accuracy is degraded

Operational at VREF \approx 0 to 0.3 V, but accuracy is degraded

(3) STEP input can operate up to 1 MHz, but system bandwidth is limited by the motor load

(4) Power dissipation and thermal limits must be observed

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6.4 Thermal Information

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report, [SPRA953.](http://www.ti.com/lit/pdf/spra953)

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6.5 Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

(1) Specified by design and characterization data

Electrical Characteristics (continued)

over operating free-air temperature range (unless otherwise noted)

(2) Specified by design and characterization data

6.6 Indexer Timing Requirements

(1) STEP input can operate up to 1 MHz, but system bandwidth is limited by the motor load

Figure 1. Timing Diagram

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6.7 Typical Characteristics

Over recommended operating conditions (unless otherwise noted)

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Typical Characteristics (continued)

Over recommended operating conditions (unless otherwise noted)

7 Detailed Description

7.1 Overview

The DRV8880 is an integrated motor driver solution for bipolar stepper motors. The device integrates two NMOS H-bridges, current regulation circuitry, and a microstepping indexer. The DRV8880 can be powered with a supply voltage between 6.5 and 45 V, and is capable of providing an output current up to 2.5 A peak current, 2.0 A fullscale current, or 1.4 A rms current. Actual operable full-scale and rms current will depend on ambient temperature, supply voltage, and PCB ground plane size. Between VM = 6.4 V and VM = 4.9 V the H-bridge outputs are shut down, but the internal logic remains active in order to prevent missed steps.

A simple STEP/DIR interface allows easy interfacing to the controller circuit. The internal indexer is able to execute high-accuracy microstepping without requiring the processor to control the current level. The indexer is capable of full step and half step as well as microstepping to 1/4, 1/8, and 1/16. In addition to the standard half stepping mode, a non-circular 1/2-stepping mode is avaialble for increased torque output at higher motor rpm.

The current regulation is highly configurable, with several decay modes of operation. The decay mode can be selected as a fixed slow, slow/mixed, mixed, slow/fast, or fast decay. The slow/mixed decay mode uses slow decay on increasing steps and mixed decay on decreasing steps. Similarly, the slow/fast decay mode uses slow decay on increasing steps and fast decay on decreasing steps.

In addition, an AutoTune mode can be used which automatically adjusts the decay setting to minimize current ripple while still reacting quickly to step changes. This feature greatly simplifies stepper driver integration into a motor drive system.

The PWM off-time, t_{OFF} , can be adjusted to 10, 20, or 30 μ s.

An adaptive blanking time feature automatically scales the minimum drive time with output current. This helps alleviate zero-crossing distortion by limiting the drive time at low-current steps.

A torque DAC feature allows the controller to scale the output current without needing to scale the analog reference voltage input VREF. The torque DAC is accessed using digital input pins. This allows the controller to save power by decreasing the current consumption when not required.

A low-power sleep mode is included which allows the system to save power when not driving the motor.

7.2 Functional Block Diagram

7.3 Feature Description

7.3.1 Stepper Motor Driver Current Ratings

Stepper motor drivers can be classified using three different numbers to describe the output current: peak, rms, and full-scale.

7.3.1.1 Peak Current Rating

The peak current in a stepper driver is limited by the overcurrent protection trip threshold I_{QCD} . The peak current describes any transient duration current pulse, for example when charging capacitance, when the overall duty cycle is very low. In general the minimum value of I_{OCP} specifies the peak current rating of the stepper motor driver. For the DRV8880, the peak current rating is 2.5 A per bridge.

7.3.1.2 RMS Current Rating

The rms (average) current is determined by the thermal considerations of the IC. The rms current is calculated based on the $R_{DS(ON)}$, rise and fall time, PWM frequency, device quiescent current, and package thermal performance in a typical system at 25°C. The real operating rms current may be higher or lower depending on heatsinking and ambient temperature. For the DRV8880, the rms current rating is 1.4 A per bridge.

7.3.1.3 Full-Scale Current Rating

The full-scale current describes the top of the sinusoid current waveform while microstepping. Since the sineusoid amplitude is related to the rms current, the full-scale current is also determined by the thermal considerations of the IC. The full-scale current rating is approximately $\sqrt{2} \times I_{rms}$. The full-scale current is set by VREF, the sense resistor, and Torque DAC when configuring the DRV8880 , see *Current [Regulation](#page-17-0)* for details. For the DRV8880, the full-scale current rating is 2.0 A per bridge.

Figure 12. Full-Scale and rms Current

Feature Description (continued)

7.3.2 PWM Motor Drivers

The DRV8880 contains drivers for two full H-bridges. A block diagram of the circuitry is shown in [Figure](#page-14-0) 13.

Figure 13. PWM Motor Driver Block Diagram

7.3.3 Microstepping Indexer

Built-in indexer logic in the DRV8880 allows a number of different stepping configurations. The Mx pins are used to configure the stepping format as shown in [Table](#page-14-1) 1.

Table 1. Microstepping Settings

[Table](#page-15-0) 2 shows the relative current and step directions for full-step through 1/16-step operation. The AOUT current is the sine of the electrical angle; BOUT current is the cosine of the electrical angle. Positive current is defined as current flowing from xOUT1 to xOUT2 while driving.

At each rising edge of the STEP input the indexer travels to the next state in the table. The direction is shown with the DIR pin logic high. If the DIR pin is logic low, the sequence is reversed.

Note that if the step mode is changed while stepping, the indexer will advance to the next valid state for the new MODE setting at the rising edge of STEP.

The home state is an electrical angle of 45°. This state is entered after power-up, after exiting logic undervoltage lockout, or after exiting sleep mode. This is shown in [Table](#page-15-0) 2 with the highlighted row.

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Table 2. Microstepping Relative Current Per Step

Table 2. Microstepping Relative Current Per Step (continued)

Non-circular 1/2–step operation is shown in [Table](#page-16-0) 3. This stepping mode consumes more power than circular 1/2-step operation, but provides a higher torque at high motor rpm.

Table 3. Non-Circular 1/2-Stepping Current

7.3.4 Current Regulation

The current through the motor windings is regulated by an adjustable fixed-off-time PWM current regulation circuit. When an H-bridge is enabled, current rises through the winding at a rate dependent on the DC voltage, inductance of the winding, and the magnitude of the back EMF present. After the current hits the current chopping threshold, the bridge enters a decay mode for a fixed period of time to decrease the current, which is configurable between 10 and 30 µs through the tri-level input TOFF. After the off time expires, the bridge is reenabled, starting another PWM cycle.

The PWM chopping current is set by a comparator which compares the voltage across a current sense resistor connected to the xISEN pin with a reference voltage. To generate the reference voltage for the current chopping comparator, the output of a sine lookup table is applied to a sine-weighted DAC, whose full-scale output voltage is set by VREF. This voltage is attenuated by a factor of Av. In addition, the TRQx pins further scale the reference.

Figure 14. Current Regulation Block Diagram

The full-scale (100%) chopping current is calculated as follows:

$$
I_{FS}(A) = \frac{VREF (V) \times TRQ (\%)}{A_V \times R_{SENSE} (\Omega)} = \frac{VREF (V) \times TRQ (\%)}{6.6 \times R_{SENSE} (\Omega)}
$$
(1)

The TRQx pins are the inputs to a Torque DAC used to scale the output current. The current scalar value for different inputs is shown below.

[Table](#page-18-0) 6 gives the xISEN trip voltage at a given DAC code and TRQ[1:0] setting for 1/16 step mode. In this table, VREF = 3.3 V.

Table 6. xISEN Trip Voltages over Torque DAC and Microsteps

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7.3.5 Decay Modes

A fixed decay mode is selected by setting the tri-level DECAYx pins as shown in [Table](#page-19-0) 7. Please note that if the ATE pin is logic high, the DECAYx pins are ignored and AutoTune is used.

Increasing and decreasing current are defined in the chart below. For the Slow/Mixed decay mode, the decay mode is set as slow during increasing current steps and mixed decay during decreasing current steps. In full step mode, the increasing step decay mode is always used.

Figure 15. Definition of Increasing and Decreasing Steps

7.3.5.1 Mode 1: Slow Decay for Increasing and Decreasing Current

Figure 16. Slow/Slow Decay Mode

During slow decay, both of the low-side FETs of the H-bridge are turned on, allowing the current to be recirculated.

Slow decay exhibits the least current ripple of the decay modes for a given t_{OFF}. However on decreasing current steps, slow decay will take a long time to settle to the new ITRIP level because the current decreases very slowly.

In cases where current is held for a long time (no input in the STEP pin) or at very low stepping speeds, slow decay may not properly regulate current because no back-EMF is present across the motor windings. In this state, motor current can rise very quickly, and may require a large off-time. In some cases this may cause a loss of current regulation, and a more aggressive decay mode is recommended.

7.3.5.2 Mode 2: Slow Decay for Increasing Current, Mixed Decay for Decreasing current

Figure 17. Slow/Mixed Decay Mode

Mixed decay begins as fast decay for a time, followed by slow decay for the remainder of t_{OFF} . In this mode, mixed decay only occurs during decreasing current. Slow decay is used for increasing current.

This mode exhibits the same current ripple as slow decay for increasing current, since for increasing current, only slow decay is used. For decreasing current, the ripple is larger than slow decay, but smaller than fast decay. On decreasing current steps, mixed decay will settle to the new I_{TRIP} level faster than slow decay.

In cases where current is held for a long time (no input in the STEP pin) or at very low stepping speeds, slow decay may not properly regulate current because no back-EMF is present across the motor windings. In this state, motor current can rise very quickly, and may require a large off-time. In some cases this may cause a loss of current regulation, and a more aggressive decay mode is recommended.

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7.3.5.3 Mode 3: Mixed Decay for Increasing and Decreasing Current

Figure 18. Mixed/Mixed Decay Mode

Mixed decay begins as fast decay for a time, followed by slow decay for the remainder of t_{OFF} . In this mode, mixed decay occurs for both increasing and decreasing current steps.

This mode exhibits ripple larger than slow decay, but smaller than fast decay. On decreasing current steps, mixed decay will settle to the new I_{TRIP} level faster than slow decay.

In cases where current is held for a long time (no input in the STEP pin) or at very low stepping speeds, slow decay may not properly regulate current because no back-EMF is present across the motor windings. In this state, motor current can rise very quickly, and requires an excessively large off-time. Increasing/decreasing mixed decay mode allows the current level to stay in regulation when no back-EMF is present across the motor windings.

 ${\rm t}_{\sf DRIVE}$

7.3.5.4 Mode 4: Slow Decay for Increasing Current, Fast Decay for Decreasing current

 I_{TRIP}

 \star t_{DRIVE} \star

During fast decay, the polarity of the H-bridge is reversed. The H-bridge will be turned off as current approaches zero in order to prevent current flow in the reverse direction. In this mode, fast decay only occurs during decreasing current. Slow decay is used for increasing current.

Fast decay exhibits the highest current ripple of the decay modes for a given t_{OFF} . Transition time on decreasing current steps is much faster than slow decay since the current is allowed to decrease much faster.

 t_{DRIVE}

7.3.5.5 Mode 5: Fast Decay for Increasing and Decreasing Current

Figure 20. Fast/Fast Decay Mode

During fast decay, the polarity of the H-bridge is reversed. The H-bridge will be turned off as current approaches zero in order to prevent current flow in the reverse direction.

Fast decay exhibits the highest current ripple of the decay modes for a given t_{OFF} . Transition time on decreasing current steps is much faster than slow decay since the current is allowed to decrease much faster.

7.3.6 AutoTune

To enable the AutoTune mode, pull the ATE pin logic high. Ensure the DECAYx pins are logic low. The AutoTune mode is registered internally when exiting from sleep mode or the power-up sequence. The ATE pin can be shorted to V3P3 to pull it logic high for this purpose.

AutoTune greatly simplifies the decay mode selection by automatically configuring the decay mode between slow, mixed, and fast decay. In mixed decay, AutoTune dynamically adjusts the fast decay percentage of the total mixed decay time. This feature eliminates motor tuning by automatically determining the best decay setting that results in the lowest ripple for the motor.

The decay mode setting is optimized iteratively each PWM cycle. If the motor current overshoots the target trip level, then the decay mode becomes more aggressive (add fast decay percentage) on the next cycle in order to prevent regulation loss. If there is a long drive time to reach the target trip level, the decay mode becomes less aggressive (remove fast decay percentage) on the next cycle in order to operate with less ripple and more efficiently. On falling steps, AutoTune will automatically switch to fast decay in order to reach the next step quickly.

AutoTune will automatically adjust the decay scheme based on operating factors like:

- Motor winding resistance and inductance
- Motor aging effects
- Motor dynamic speed and load
- Motor supply voltage variation
- Motor back-EMF difference on rising and falling steps
- Step transitions
- Low-current vs. high-current dl/dt

7.3.7 Adaptive Blanking Time

After the current is enabled in an H-bridge, the voltage on the xISEN pin is ignored for a period of time before enabling the current sense circuitry. Note that the blanking time also sets the minimum drive time of the PWM.

The blanking time is automatically scaled so that the drive time is reduced at lower current steps.

The time $t_{B|ANK}$ is determined by the sine DAC code and the torque DAC setting. The timing information for $t_{BI,ANK}$ is given in [Table](#page-25-1) 8.

Table 8. Adaptive Blanking Time Settings over Torque DAC and Microsteps

SINE DAC CODE	TORQUE DAC TRQ[1:0] SETTING			
	$00 - 100\%$	$01 - 75%$	$10 - 50%$	$11 - 25%$
16	$1.80 \,\mu s$	$1.50 \,\mathrm{\mu s}$	$1.50 \,\mu s$	$1.20 \,\mu s$
15	$1.80 \,\mu s$	$1.50 \,\mu s$	$1.50 \,\mu s$	$1.20 \,\mu s$
14	$1.80 \,\mu s$	$1.50 \,\mu s$	$1.50 \,\mu s$	$1.20 \,\mu s$
13	$1.80 \,\mu s$	$1.50 \,\mu s$	$1.50 \,\mu s$	$1.20 \,\mu s$
12	$1.80 \,\mu s$	$1.50 \,\mu s$	$1.50 \,\mu s$	$1.20 \,\mu s$
11	$1.80 \,\mu s$	$1.50 \,\mu s$	$1.50 \,\mu s$	$1.20 \,\mu s$
10	$1.80 \,\mu s$	$1.50 \,\mu s$	$1.50 \,\mu s$	$1.20 \,\mu s$
9	$1.80 \,\mu s$	$1.50 \,\mu s$	$1.50 \,\mu s$	$1.20 \,\mu s$
8	$1.50 \,\mu s$	$1.50 \,\mu s$	$1.20 \,\mu s$	$0.90 \,\mu s$
7	$1.50 \,\mu s$	$1.50 \,\mathrm{\mu s}$	$1.20 \,\mathrm{\mu s}$	$0.90 \,\mu s$
6	$1.50 \,\mathrm{\mu s}$	$1.50 \,\mu s$	$1.20 \mu s$	$0.90 \,\mu s$
5	$1.50 \,\mu s$	$1.50 \,\mu s$	$1.20 \,\mu s$	$0.90 \,\mu s$
4	$1.20 \,\mathrm{\mu s}$	$1.20 \,\mathrm{\mu s}$	$0.90 \,\mathrm{\mu s}$	$0.90 \,\mu s$
3	$1.20 \,\mu s$	$1.20 \,\mu s$	$0.90 \,\mu s$	$0.90 \,\mu s$
2	$0.90 \,\mu s$	$0.90 \,\mu s$	$0.90 \mu s$	$0.90 \,\mu s$
1	$0.90 \,\mu s$	$0.90 \,\mu s$	$0.90 \,\mu s$	$0.90 \,\mu s$

7.3.8 Charge Pump

A charge pump is integrated in order to supply a high-side NMOS gate drive voltage. The charge pump requires a capacitor between the VM and VCP pins. Additionally a low-ESR ceramic capacitor is required between pins CPH and CPL.

Figure 21. Charge Pump Diagram

7.3.9 LDO Voltage Regulator

An LDO regulator is integrated into the DRV8880. It can be used to provide the supply voltage for low-current devices. For proper operation, bypass V3P3 to GND using a ceramic capacitor.

The V3P3 output is nominally 3.3 V. When the V3P3 LDO current load exceeds 10 mA, the LDO will behave like a constant current source. The output voltage will drop significantly with currents greater than 10 mA.

Figure 22. LDO Diagram

If a digital input needs to be tied permanently high (that is, M or TOFF), it is preferable to tie the input to V3P3 instead of an external regulator. This will save power when VM is not applied or in sleep mode: V3P3 is disabled and current will not be flowing through the input pulldown resistors. For reference, logic level inputs have a typical pulldown of 100 kΩ, and tri-level inputs have a typical pulldown of 40 kΩ.

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7.3.10 Logic and Tri-Level Pin Diagrams

The diagram below gives the input structure for logic-level pins STEP, DIR, ENABLE, nSLEEP, TRQ0, TRQ1, and ATE:

Figure 23. Logic-level Input Pin Diagram

Tri-level logic pins TOFF, M0, M1, DECAY0, and DECAY1 have the following structure:

Figure 24. Tri-level Input Pin Diagram

7.3.11 Protection Circuits

The DRV8880 is fully protected against undervoltage, charge pump undervoltage, overcurrent, and overtemperature events.

7.3.12 VM UVLO (UVLO2)

If at any time the voltage on the VM pin falls below the VM undervoltage lockout threshold voltage (V_{UVLO2}), all FETs in the H-bridge will be disabled, the charge pump will be disabled, and the nFAULT pin will be driven low. Operation will resume when VM rises above the UVLO2 threshold. The nFAULT pin will be released after operation has resumed.

The indexer position is not reset by this fault even though the output drivers are disabled. The indexer position is maintained and internal logic remains active until VM falls below the logic undervoltage threshold ($V_{U\cup(1)}$).

7.3.13 Logic Undervoltage (UVLO1)

If at any time the voltage on the VM pin falls below the logic undervoltage threshold voltage ($V_{U|V|Q1}$), the internal logic is reset, and the V3P3 regulator is disabled. Operation will resume when VM rises above the UVLO1 threshold. The nFAULT pin is logic low during this state since it is pulled low upon encountering VM undervoltage. Decreasing VM below this undervoltage threshold will reset the indexer position.

7.3.14 VCP Undervoltage Lockout (CPUV)

If at any time the voltage on the VCP pin falls below the charge pump undervoltage lockout threshold voltage, all FETs in the H-bridge will be disabled and the nFAULT pin will be driven low. Operation will resume when VCP rises above the CPUV threshold. The nFAULT pin will be released after operation has resumed.

7.3.15 Thermal Shutdown (TSD)

If the die temperature exceeds safe limits, all FETs in the H-bridge will be disabled and the nFAULT pin will be driven low. Once the die temperature has fallen to a safe level operation will automatically resume. The nFAULT pin will be released after operation has resumed.

7.3.16 Overcurrent Protection (OCP)

An analog current limit circuit on each FET limits the current through the FET by removing the gate drive. If this analog current limit persists for longer than t_{OCP} , all FETs in the H-bridge will be disabled and nFAULT will be driven low. In addition to this FET current limit, an overcurrent condition is also detected if the voltage at xISEN exceeds V_{OCP} .

The overcurrent fault response can be set to either latched mode or retry mode:

Figure 25. Latched OCP Mode Figure 26. Retry OCP Mode

In latched mode, operation will resume after the ENABLE pin is brought logic low for at least 1 μs to reset the output driver. The nFAULT pin will be released after ENABLE is returned logic high. Removing and re-applying VM or toggling nSLEEP will also reset the latched fault.

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In retry mode, the driver will be re-enabled after the OCP retry period (t_{RETRY}) has passed. nFAULT becomes high again after the retry time. If the fault condition is still present, the cycle repeats. If the fault is no longer present, normal operation resumes and nFAULT remains deasserted.

A microcontroller can retain control of the ENABLE pin while in retry mode if it is operated like an open-drain output. Many microcontrollers support this. When the DRV8880 is operating normally, configure the MCU GPIO as an input. In this state, the MCU can detect whenever nFAULT is pulled low. In order to disable the DRV8880 output, configure the GPIO output state as low, and then configure the GPIO as an output.

Alternatively, a logic-level FET may be used to create an open drain external to the MCU. In this case, an additional MCU GPIO may be required in order to monitor the nFAULT pin.

Figure 27. Methods For Operating in Retry Mode

Table 9. Fault Condition Summary

7.4 Device Functional Modes

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The DRV8880 internal logic, indexer, and charge pump are operating unless the nSLEEP pin is brought logic low. In sleep mode the charge pump is disabled, the H-bridge FETs are disabled Hi-Z, and the V3P3 regulator is disabled. t_{SLEEP} must elapse after a falling edge on the nSLEEP pin before the device is in sleep mode. The DRV8880 is brought out of sleep mode automatically if nSLEEP is brought logic high. t_{WAKE} must elapse before the outputs change state after wake-up.

If the ENABLE pin is brought logic low, the H-bridge outputs are disabled, but the charge pump and internal logic will remian active. A rising edge on STEP will advance the indexer, but the outputs will not change state until ENABLE brought logic high.

When VM falls below the VM undervoltage lockout threshold V_{UVLO2} , the output driver and charge pump are disabled, but the internal logic and V3P3 remain active. In this mode, STEP inputs will advance the indexer, but the outputs will remain disabled. If VM falls below the logic undervoltage threshold V_{UVLO1} , the internal logic is reset and the indexer will lose position.

Table 10. Functional Modes Summary

8 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The DRV8880 is used in stepper control.

8.2 Typical Application

The following design procedure can be used to configure the DRV8880.

Figure 28. Typical Application Schematic

8.2.1 Design Requirements

[Table](#page-31-3) 11 gives design input parameters for system design.

8.2.2 Detailed Design Procedure

8.2.2.1 Stepper Motor Speed

The first step in configuring the DRV8880 requires the desired motor speed and microstepping level. If the target application requires a constant speed, then a square wave with frequency f_{step} must be applied to the STEP pin.

If the target motor speed is too high, the motor will not spin. Make sure that the motor can support the target speed.

For a desired motor speed (v), microstepping level (n_m), and motor full step angle (θ_{step}),

$$
f_{\text{step}} \text{ (steps / s)} = \frac{v \text{ (rpm)} \times 360 \text{ (}^{\circ} \text{/ rot)} \text{ (step 1 - 360 (} \text{ (green 1)} \times 60 \text{ (s / min)} \text{)}
$$
\n
$$
\tag{2}
$$

 θ_{step} can be found in the stepper motor data sheet or written on the motor itself.

For the DRV8880, the microstepping level is set by the Mx pins and can be any of the settings in the table below. Higher microstepping will mean a smother motor motion and less audible noise, but will increase switching losses and require a higher f_{step} to achieve the same motor speed.

Table 12. Microstepping Indexer Settings

M ₁	M ₀	STEP MODE
	O	Full step (2-phase excitation) with 71% current
		Non-circular 1/2 step
	O	$1/2$ step
		$1/4$ step
	7	$1/8$ step
		$1/16$ step

Example: Target 120 rpm at 1/8 microstep mode. The motor is 1.8°/step

$$
f_{\text{step}}\text{ (steps / s)} = \frac{120 \text{ rpm} \times 360^{\circ} / \text{rot}}{1.8^{\circ} / \text{step} \times 1/8 \text{ steps} / \text{microstep} \times 60 \text{ s} / \text{min}} = 3.2 \text{ kHz}
$$
\n(3)

8.2.2.2 Current Regulation

In a stepper motor, the full-scale current (I_{FS}) is the maximum current driven through either winding. This quantity will depend on the TRQ pins, the VREF analog voltage, and the sense resistor value (R_{SENSE}). During stepping, I_{FS} defines the current chopping threshold (I_{TRIP}) for the maximum current step.

$$
I_{FS}(A) = \frac{VREF(V) \times TRQ(\%)}{A_V \times R_{SENSE}(\Omega)} = \frac{VREF(V) \times TRQ(\%)}{6.6 \times R_{SENSE}(\Omega)}
$$

TRQ is a DAC used to scale the output current. The current scalar value for different inputs is shown below.

Table 13. Torque DAC Settings

(4)

Example: If the desired full-scale current is 1.5 A

Set R_{SENSE} = 100 mΩ, assume TRQ = 100%.

VREF would have to be 0.99 V.

Create a resistor divider from V3P3 (3.3 V) to set VREF \approx 0.99 V.

Set R2 = 10 kΩ, set R1 = 22 kΩ

Note that I_{FS} must also follow the equation below in order to avoid saturating the motor. VM is the motor supply voltage, and R_L is the motor winding resistance.

$$
I_{FS}(A) < \frac{VM(V)}{R_{L}(\Omega) + 2 \times R_{DS(ON)}(\Omega) + R_{SENSE}(\Omega)}
$$

8.2.2.3 Decay Modes

The DRV8880 supports several different decay modes: slow decay, fast decay, mixed decay, and AutoTune. The current through the motor windings is regulated using an adjustable fixed-time-off scheme. This means that after any drive phase, when a motor winding current has hit the current chopping threshold (I_{TRIP}), the DRV8880 will place the winding in one of the decay modes for t_{OFF}. After t_{OFF}, a new drive phase starts. For fixed decay modes (slow, fast, and mixed), the best setting can be determined by operating the motor and choosing the best setting.

8.2.2.4 Sense Resistor

For optimal performance, it is important for the sense resistor to be:

- Surface-mount
- Low inductance
- Rated for high enough power
- Placed closely to the motor driver

The power dissipated by the sense resistor equals $I_{\rm rms}$ 2 x R. For example, if the rms motor current is 1.4A and a 250 mΩ sense resistor is used, the resistor will dissipate 1.4 A² x 0.25 Ω = 0.49 W. The power quickly increases with higher current levels.

Resistors typically have a rated power within some ambient temperature range, along with a derated power curve for high ambient temperatures. When a PCB is shared with other components generating heat, margin should be added. It is always best to measure the actual sense resistor temperature in a final system, along with the power MOSFETs, as those are often the hottest components.

Because power resistors are larger and more expensive than standard resistors, it is common practice to use multiple standard resistors in parallel, between the sense node and ground. This distributes the current and heat dissipation.

(5)

8.2.3 Application Curves

9 Power Supply Recommendations

The DRV8880 is designed to operate from an input voltage supply (VM) range between 6.5 V and 45 V. The device has an absolute maximum rating of 50 V. A 0.1-µF ceramic capacitor rated for VM must be placed at each VM pin as close to the DRV8880 as possible. In addition, a bulk capacitor must be included on VM.

9.1 Bulk Capacitance Sizing

Having appropriate local bulk capacitance is an important factor in motor drive system design. It is generally beneficial to have more bulk capacitance, while the disadvantages are increased cost and physical size.

The amount of local capacitance needed depends on a variety of factors, including:

- The highest current required by the motor system
- The power supply's capacitance and ability to source current
- The amount of parasitic inductance between the power supply and motor system
- The acceptable voltage ripple
- The type of motor used (brushed DC, brushless DC, stepper)
- The motor braking method

The inductance between the power supply and motor drive system will limit the rate current can change from the power supply. If the local bulk capacitance is too small, the system will respond to excessive current demands or dumps from the motor with a change in voltage. When adequate bulk capacitance is used, the motor voltage remains stable and high current can be quickly supplied.

The data sheet generally provides a recommended value, but system-level testing is required to determine the appropriate sized bulk capacitor.

The voltage rating for bulk capacitors should be higher than the operating voltage, to provide margin for cases when the motor transfers energy to the supply.

Figure 35. Setup of Motor Drive System With External Power Supply

10 Layout

10.1 Layout Guidelines

Each VM terminal must be bypassed to GND using a low-ESR ceramic bypass capacitors with recommended values of 0.1 μF rated for VM. These capacitors should be placed as close to the VM pins as possible with a thick trace or ground plane connection to the device GND pin.

The VM pin must be bypassed to ground using a bulk capacitor rated for VM. This component may be an electrolytic.

A low-ESR ceramic capacitor must be placed in between the CPL and CPH pins. A value of 0.1 μF rated for VM is recommended. Place this component as close to the pins as possible.

A low-ESR ceramic capacitor must be placed in between the VM and VCP pins. A value of 0.47 μF rated for 16 V is recommended. Place this component as close to the pins as possible.

Bypass V3P3 to ground with a ceramic capacitor rated 6.3 V. Place this bypassing capacitor as close to the pin as possible.

The current sense resistors should be placed as close as possible to the device pins in order to minimize trace inductance between the pin and resistor.

10.2 Layout Example

Figure 36. Layout Recommendation

11 Device and Documentation Support

11.1 Documentation Support

11.1.1 Related Documentation

- *PowerPAD™ Thermally Enhanced Package*, [SLMA002](http://www.ti.com/lit/pdf/SLMA002)
- *PowerPAD™ Made Easy*, [SLMA004](http://www.ti.com/lit/pdf/SLMA004)
- *Current Recirculation and Decay Modes*, [SLVA321](http://www.ti.com/lit/pdf/SLVA321)
- *Calculating Motor Driver Power Dissipation*, [SLVA504](http://www.ti.com/lit/pdf/SLVA504)
- *Understanding Motor Driver Current Ratings*, [SLVA505](http://www.ti.com/lit/pdf/SLVA505)

11.2 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms](http://www.ti.com/corp/docs/legal/termsofuse.shtml) of [Use.](http://www.ti.com/corp/docs/legal/termsofuse.shtml)

TI E2E™ Online [Community](http://e2e.ti.com) *TI's Engineer-to-Engineer (E2E) Community.* Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design [Support](http://support.ti.com/) *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

11.3 Trademarks

AutoTune, E2E are trademarks of Texas Instruments. All other trademarks are the property of their respective owners.

11.4 Electrostatic Discharge Caution

These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

11.5 Glossary

[SLYZ022](http://www.ti.com/lit/pdf/SLYZ022) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check<http://www.ti.com/productcontent>for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

www.ti.com 13-Sep-2015

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PACKAGE MATERIALS INFORMATION

Texas
Instruments

TAPE AND REEL INFORMATION

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

TEXAS
INSTRUMENTS

PACKAGE MATERIALS INFORMATION

www.ti.com 14-Sep-2015

*All dimensions are nominal

PWP (R-PDSO-G28)

PowerPAD[™] PLASTIC SMALL OUTLINE

All linear dimensions are in millimeters. NOTES: A.

- This drawing is subject to change without notice. В.
- Body dimensions do not include mold flash or protrusions. Mold flash and protrusion shall not exceed 0.15 per side. C.
- This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad D. Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding
recommended board layout. This document is available at www.ti.com <http://www.ti.com>.
E. See the additional figure in the Pro
	-
- E. Falls within JEDEC MO-153

PowerPAD is a trademark of Texas Instruments.

PowerPADTM SMALL PLASTIC OUTLINE $PWP (R-PDSO-G28)$

THERMAL INFORMATION

This PowerPADTM package incorporates an exposed thermal pad that is designed to be attached to a printed circuit board (PCB). The thermal pad must be soldered directly to the PCB. After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached
directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the PowerPAD package and how to take advantage of its heat dissipating
abilities, refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD Made Easy, Texas Instruments Literature No. SLMA004. Both documents are available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.

 $\overline{\mathbb{B}}$ Exposed tie strap features may not be present.

PowerPAD is a trademark of Texas Instruments

NOTES:

A. All linear dimensions are in millimeters.

- This drawing is subject to change without notice. **B.**
- Customers should place a note on the circuit board fabrication drawing not to alter the center C_{\cdot} solder mask defined pad.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002, SLMA004, and also the Product Data Sheets.
- E. For specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <http://www.ti.com>. Publication IPC-7351 is recommended for alternate designs. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil
- F. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

MECHANICAL DATA

B. This drawing is subject to change without notice.

 $\mathbb{C}.$ QFN (Quad Flatpack No-Lead) package configuration.

⚠ The package thermal pad must be soldered to the board for thermal and mechanical performance.

Reference JEDEC MO-220. E.

RHR (R-PWQFN-N28)

PLASTIC QUAD FLATPACK NO-LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.

NOTE: Α. All linear dimensions are in millimeters

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